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Contents

Editorial vii
Committees and Sponsors ix
Photo x
Contents xi

Scattering, stopping and related processes

Valence structure effects in the stopping of swift ions
P. Sigmund, A. Sharma, A. Schinner and A. Fettouhi 1
Non-unitary master equation for the internal state of ions traversing solids
M. Seliger, C.O. Reinhold, T. Minami and J. Burgdörfer 7
Pair production and bremsstrahlung contributions to the stopping of relativistic heavy ions
A.H. Sørensen 12
Impact-parameter dependence of the electronic energy loss of fast cluster projectiles
R.C. Fadanelli, P.L. Grande and G. Schiwietz 17
Stopping power and Cherenkov radiation in photonic crystals
N. Zabala, F.J. García de Abajo, A. Rivacoba, A.G. Pattantyus-Abraham, M.O. Wolf, L.A. Blanco and P.M. Echenique 24
Dynamic response of target electrons upon low and medium energy ion impact
T. Okazawa, Y. Hoshino, T. Nishimura, K. Umezawa, S. Nakanishi and Y. Kido 31
Recombination of H_2^+ molecules in channeling conditions
C.D. Denton, J. Díaz-Valdés, J.E. Valdés, P. Vargas and N.R. Arista 36
Wake effects in the evolution of fast molecular ions through thin foils
R. Garcia-Molina, I. Abril, S. Heredia-Avalos, L. Lammich, H. Buhr, H. Kreckel, S. Krohn, D. Strasser, R. Wester, A. Wolf, D. Zajfman and D. Schwalm 41
Pressure dependence of the mean excitation energy of atomic systems
S.A. Cruz, C. Díaz-García, A.P. Pathak and J. Soullard 46
Angular dispersion of protons passing through thin metallic films
C.D. Archubi, C.D. Denton, J.C. Eckardt, G.H. Lantschner, N.R. Arista, J.E. Valdés and J. Ferrón .. 53
An experimental evaluation of spatial distribution for deeply penetrating protons in carbon material
M. Tosaki, D. Ohsawa and Y. Isozumi 59
Charge state distribution and its equilibration of 2 MeV/u sulfur ions passing through carbon foils
M. Imai, M. Sataka, K. Kawatsura, K. Takahiro, K. Komaki, H. Shibata, H. Sugai and K. Nishio... 63
Mean excitation energies extracted from stopping power measurements of protons in polymers by using the modified Bethe–Bloch formula
H. Ammi, R. Zemih, S. Mammeri and M. Allab 68

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Energy loss calculations for fast light ions in celluloid including charge-exchange processes
Ya.A. Teplova, Yu.A. Belkova and O.A. Yuminov 73
Modeling the energy and momentum dependent loss function of the valence shells of liquid water
D. Emfietzoglou, A. Pathak and M. Moscovitch 77
X-ray yields from high-energy heavy ions channeled through a crystal: their crystal thickness and projectile dependences
C. Kondo, Y. Takabayashi, T. Muranaka, S. Masugi, T. Azuma, K. Komaki, A. Hatakeyama, Y. Yamazaki, E. Takada and T. Murakami 85
Resonant coherent excitation of 2s electron of Li-like Fe ions to the $n = 3$ states
Y. Nakai, T. Ikeda, Y. Kanai, T. Kambara, N. Fukunishi, K. Komaki, C. Kondo, T. Azuma and Y. Yamazaki 90
The influence of the Coulomb explosion on the energy loss of H_2^+ and H_3^+ molecules channeling along the Si ⟨1 0 0⟩ direction
R.C. Fadanelli, P.L. Grande, M. Behar, J.F. Dias and G. Schiwietz 96
Dechanneling of electrons by stacking faults – a model quantum mechanical calculation
S. Dhamodaran, N. Sathish, A.P. Pathak, L.N.S. Prakash Goteti, S.V.S. Nageswara Rao, V. Raghav Rao and D. Emfietzoglou 100
Angular distributions of 1 GeV protons channeled in bent short single-wall carbon nanotubes
N. Nešković, S. Petrović and D. Borka 106
Atomistic simulation of ion channeling in heavily doped Si:As
A. Satta, E. Albertazzi, M. Bianconi, G. Lulli, S. Balboni and L. Colombo 112
Energy loss of H^+ and He^+ in the semiconductors GaAs, ZnSe, InP and SiC
S. Heredia-Avalos, J.C. Moreno-Marín, I. Abril and R. Garcia-Molina 118
Surface excitation parameter for semiconducting III–V compounds
C.M. Kwei, Y.H. Tu and C.J. Tung 125
Dependence of damage efficiency of ions in diamond on electronic stopping
E. Friedland, H.D. Carstanjen, G. Myburg and M.A. Nasr 129
Ion-velocity dependence of high-density electronic excitation effects in oxide superconductors
N. Ishikawa, Y. Chimi, O. Michikami, T. Hashimoto, T. Kambara, R. Neumann and A. Iwase 136
Dynamic interactions of fast ions with carbon nanotubes
D.J. Mowbray, S. Chung, Z.L. Mišković, F.O. Goodman and Y.-N. Wang 142
Energy loss of ions interacting with metal surfaces
J.I. Juaristi 148
Theoretical study of swift molecular ions specularly reflected from solid surfaces under glancing angle of incidence
Y.-H. Song, Y.-N. Wang and Z.L. Mišković 158
Channeling regimes in ion surface scattering
A. Robin and W. Heiland 165
Interatomic potentials from rainbow scattering of keV noble gas atoms under axial surface channeling
A. Schüller, S. Wethekam, A. Mertens, K. Maass, H. Winter and K. Gärtner 172
Specular reflection model study of the image effect in He^+/a:Si scattering at low energy
A. Hidouche, A.C. Chami, Y. Boudouma, M. Boudjema and C. Benazeth 178

Material processes in the bulk

Channeling characterization of defects in silicon: an atomistic approach
M. Bianconi, E. Albertazzi, S. Balboni, L. Colombo, G. Lulli and A. Satta 185
Formation processes of nickel oxide nanoparticles in SiO_2 by metal-ion implantation combined with thermal oxidation
H. Amekura, N. Umeda, Y. Takeda, J. Lu, K. Kono and N. Kishimoto 193

Effect of Si implantation on the microstructure of silicon nanocrystals and surrounding SiO_2 layer
G.G. Ross, R. Smirani, V. Levitcharsky, Y.Q. Wang, G. Veilleux and R.G. Saint-Jacques 198
Enhancement of luminescence from encapsulated Si nanocrystals in SiO_2 with rapid thermal anneals
T. Shimizu-Iwayama, T. Hama, D.E. Hole and I.W. Boyd 203
Planar defects in crystalline silicon caused by self-irradiation
S.T. Nakagawa and G. Betz 210
Monitoring interstitial fluxes by self-assembled nanovoids in ion-implanted Si/SiGe/Si strained structures
P.I. Gaiduk, J. Lundsgaard Hansen and A. Nylandsted Larsen 214
Interaction between implanted fluorine atoms and point defects in preamorphized silicon
G. Impellizzeri, J.H.R. dos Santos, S. Mirabella, E. Napolitani, A. Carnera and F. Priolo 220
Radiation enhanced diffusion of implanted platinum in silicon guided by helium co-implantation for arbitrary control of platinum profile
P. Hazdra and J. Vobecký 225
Radiation damage induced by 5 keV Si^+ ion implantation in strained-$Si/Si_{0.8}Ge_{0.2}$
T. Matsushita, W. Sakai, K. Nakajima, M. Suzuki, K. Kimura, A. Agarwal, H.-J. Gossmann and M. Ameen 230
Atomic mixing at metal–oxide interfaces by high energy heavy ions
R. Nakatani, R. Taniguchi, Y. Chimi, N. Ishikawa, M. Fukuzumi, Y. Kato, H. Tsuchida, N. Matsunami and A. Iwase 234
Interface mixing induced by swift heavy ions at metal-oxide/silicon interfaces
B. Schattat, W. Bolse, A. Elsanousi and T. Renz 240
Porous track cores along wakes of swift Pb ions in LiF
S. Abu Saleh and Y. Eyal 246
Color center annealing and ageing in electron and ion-irradiated yttria-stabilized zirconia
J.-M. Costantini and F. Beuneu 251
Active waveguides produced in lithium fluoride by He^+ implantation
V. Mussi, R.M. Montereali, P. Moretti, J. Mugnier, E. Nichelatti, F. Somma and B. Jacquier 257
Modification of N-doped carbon induced by 30 MeV C_{60} ions
Z.G. Wang, A. Dunlop, Z.M. Zhao, Y. Song, Y.F. Jin, C.H. Zhang, Y.M. Sun and J. Liu 262
Swift heavy ion induced magnetic phase transition of Fe–Rh alloy
M. Fukuzumi, Y. Chimi, N. Ishikawa, F. Ono, S. Komatsu and A. Iwase 269
Radiation damage effects in CMR manganite materials
S. Chattopadhyay, S. Pal, A. Sarkar, R. Kumar and B.K. Chaudhuri 274
Effect of GeV-Ion irradiation on magnetic properties of Fe–Ni invar alloys
F. Ono, S. Komatsu, Y. Chimi, N. Ishikawa, A. Iwase and T. Kambara 279
Interesting aspects of the analysis of resistivity in Li^{3+} irradiated Bi-2212
A. Sarkar, S. Chattopadhyay, R. Kumar and U. De 284

Surface processes

On the extraction of neutralisation information from low energy ion scattering spectra
M. Draxler, J.E. Valdés, R. Beikler and P. Bauer 290
Broadening effects in Auger neutralization of 130–430 eV Ar^+ ions at Al surfaces
A. Sindona, R.A. Baragiola, S. Maletta, G. Falcone, A. Oliva and P. Riccardi 298
Neutralization of keV Ne^+ and Ar^+ ions during grazing scattering from an Al(1 1 1) surface
S. Wethekam, G. Adamov and H. Winter 305
He^+ scattering on a TiO_2(1 1 0) surface
A.R. Canário, Yu. Bandourine, O. Grizzi, J. Lugo, L. Guillemot and V.A. Esaulov 311
Charge transfer in grazing scattering on clean and oxygen covered Cu(1 1 0) surfaces: velocity effects
N. Nieuwjaer, C. Bénazeth, P. Benoit-Cattin, P. Cafarelli and M. Richard-Viard 317

Resonant charge transfer in back-scattering of H-atoms from the Cs adsorbates on the Cs/Cu(1 1 1) surface
J. Sjakste, A.G. Borisov and J.P. Gauyacq 323
High negative ion yield from light molecule scattering
J.A. Scheer, M. Wieser, P. Wurz, P. Bochsler, E. Hertzberg, S.A. Fuselier, F.A. Koeck, R.J. Nemanich and M. Schleberger 330
Metastable He deexcitation at semiconductor interfaces
L. Pasquali and S. Nannarone 340
Growth and oxidation of Na on Ag(0 0 1): a MDS study
R. Moroni, M. Canepa, S. Terreni and L. Mattera 351
Surface spin polarization in Fe(1 1 0) and Ni(1 1 0)
M. Unipan, D.F.A. Winters, A. Robin, R. Morgenstern and R. Hoekstra 356
Neutralization of noble gas ions on ionic insulators: Auger neutralization or double-electron capture
P. Rousseau, M. Gugiu, H. Khemliche and P. Roncin 361
Neutralization rate for slow Ar^+ ions in front of KCl(0 0 1)
T. Tsujioka, S. Tanaka, A. Nakamoto, K. Nakajima, M. Suzuki and K. Kimura 369
Effect of Auger neutralization on yields of He ions backscattered and alkali ions sputtered from the surface of alkali halides by keV He ion impact
K. Morita and H. Gridneva 373
Path dependence of the charge state distributions of low-energy F^{q+} ions backscattered from RbI(1 0 0)
L.I. Vergara, F.W. Meyer and H.F. Krause 379
Effect of electric charge accumulation on low energy ion implantation in insulators
M. Yedji and G.G. Ross 386
Stochastic effects of charge transfer on image interaction and plasmon excitation in ion-surface grazing scattering
Z.L. Mišković, F.O. Goodman, Y.-H. Song and Y.-N. Wang 391
High resolution time-of-flight low energy ion scattering
M. Draxler, S.N. Markin, M. Kolíbal, S. Průša, T. Šikola and P. Bauer 398
Kalypso: a software package for molecular dynamics simulation of atomic collisions at surfaces
M.A. Karolewski 402
Mechanism of adatom formation on Ag(1 1 0) studied by combined quasi-elastic He atom scattering and low energy ion scattering
L. Pedemonte and G. Bracco 406
Surface and sub-surface oxidation of α-Cu-(17 at.%)Al(1 0 0) studied by X-ray photo-electron spectroscopy and low energy He^+ scattering spectroscopy
T. Kravchuk, R. Akhvlediani and A. Hoffman 413

Emission phenomena

Fermi shuttle acceleration in atomic collisions: the case of ion induced electron emission
H. Rothard, G. Lanzanò, E. De Filippo and C. Volant 419
Electronic energy-density effects in ion tracks of metals
F. Staufenbiel, G. Schiwietz, K. Czerski, M. Roth and P.L. Grande 426
Spin effects in the screening and Auger neutralization of He^+ ions in a spin-polarized electron gas
M. Alducin, R. Díez Muiño and J.I. Juaristi 431
Plasmon excitation and electron promotion in the interaction of slow Na^+ ions with Al surfaces
M. Commisso, A. Bonanno, A. Oliva, M. Camarca, F. Xu, P. Riccardi and R.A. Baragiola 438
Ion-induced electron emission – monitoring the structure transitions in graphite
A.M. Borisov, E.S. Mashkova, A.S. Nemov and E.S. Parilis 443
Resonant mechanisms for negative ionization of secondary emitted atoms from sputtered metals
A. Sindona, P. Riccardi and G. Falcone 449

Kinetic electron emission in the interactions of slow ions with MgO surfaces
P. Riccardi, P. Barone, A. Bonanno, A. Oliva, P. Vetrò, M. Ishimoto and R.A. Baragiola 455
Electron emission induced by H^+ and H^0 incident on thin carbon foils: influence of charge changing processes
N. Pauly, A. Dubus, M. Rösler, H. Rothard, A. Clouvas and C. Potiriadis 460
Influence of the target thickness on the backward and forward electron emission characteristics induced by protons incident on thin carbon foils
C. Potiriadis, A. Clouvas, H. Rothard, N. Pauly, A. Dubus and M. Rösler 466
Heavy-ion-induced luminescence of amorphous SiO_2 during nanoparticle formation
V. Bandourko, N. Umeda, O. Plaksin and N. Kishimoto 471
Angular distribution of radiation by relativistic electrons in a thin crystal
X. Artru, S.P. Fomin and N.F. Shul'ga 476
Total sputtering yields of solids under MeV-energy Si ion bombardment
S. Ninomiya, C. Imada, M. Nagai, Y. Nakata, T. Aoki, J. Matsuo and N. Imanishi 483
Secondary neutral and ionized particle measurements under MeV-energy ion bombardment
Y. Nakata, S. Ninomiya, C. Imada, M. Nagai, T. Aoki, J. Matsuo and N. Imanishi 489
Desorption of gold nanoclusters (2–150 nm) by 1 GeV Pb ions
I. Baranov, S. Kirillov, A. Novikov, V. Obnorskii, M. Toulemonde, K. Wien, S. Yarmiychuk, V.A. Borodin and A.E. Volkov 495
Analysis of the desorption of clusters of intact amino acid valine molecules induced by energetic monoatomic and cluster ions
G. Szenes 502
A multi-exciton model for the electronic sputtering of oxides
N. Matsunami, O. Fukuoka, T. Shimura, M. Sataka and S. Okayasu 507

Applications of ion beams

Submicron-scale patterns on ferromagnetic–antiferromagnetic Fe/NiO layers by focused ion beam (FIB) milling
G.C. Gazzadi, P. Luches, S.F. Contri, A. di Bona and S. Valeri 512
Spin-resolved magnetic studies of focused ion beam etched nano-sized magnetic structures
J. Li and C. Rau 518
Nanoscale self-affine surface smoothing by ion bombardment and the morphology of nanostructures grown on ion-bombarded surfaces
K. Bhattacharjee, S. Bera, D.K. Goswami and B.N. Dev 524
Fluence dependence of the surface roughness of InP after N_2^+ bombardment
J.B. Malherbe, N.G. van der Berg, F. Claudel, S.O.S. Osman, R.Q. Odendaal, F. Krok and M. Szymonski 533
Nanoscale periodic and faceted structures formation on Si(1 0 0) by oblique angle oxygen ion sputtering
P. Karmakar and D. Ghose 539
Ion sputtered surfaces as templates for carbon nanotubes alignment and deformation
F. Granone, V. Mussi, A. Toma, S. Orlanducci, M.L. Terranova, C. Boragno, F. Buatier de Mongeot and U. Valbusa 545
Ion beam erosion of amorphous materials: evolution of surface morphology
A. Toma, F. Buatier de Mongeot, R. Buzio, G. Firpo, S.R. Bhattacharyya, C. Boragno and U. Valbusa 551
Temperature dependence of rippled corrugations induced on the Rh(1 1 0) surface via ion sputtering
A. Molle, F. Buatier de Mongeot, F. Granone, R. Buzio, G. Firpo, C. Boragno and U. Valbusa 555
Low-energy ion scattering and sputtering at grazing ion bombardment of clean and oxygen covered Ag(1 1 0) surface
A.A. Dzhurakhalov, S.E. Rahmatov and I.D. Yadgarov 560
Structural stability of C_{60} films under irradiation with swift heavy ions
Y. Jin, C. Yao, Z. Wang, E. Xie, Y. Song, Y. Sun, C. Zhang, J. Liu and J. Duan 565

Competitive diffusion of gold and copper atoms in Cu/Au/Si and Au/Cu/Si annealed systems
C. Benazzouz, N. Benouattas and A. Bouabellou 571
Angular distribution of sputtered particles and surface morphology: the case of beryllium under a krypton beam at various incidences
P.-G. Fournier, A. Nourtier, V.I. Shulga and M. Ait El Fqih 577
The effect of microrelief evolution on the angular dependence of polycrystalline Cu sputtering yield
N.N. Andrianova, A.M. Borisov, E.S. Mashkova, A.S. Nemov and V.I. Shulga 583
Comparative analysis of the energy dependences of the induced fission times for the Pb-like and U-like nuclei obtained by the crystal blocking technique
V.A. Drozdov, D.O. Eremenko, O.V. Fotina, G. Giardina, F. Malaguti, S.Yu. Platonov, A.F. Tulinov, A. Uguzzoni and O.A. Yuminov 589
Measurement of diffusion coefficients in solids by the short-lived radioactive beam of ^{8}Li
S.C. Jeong, I. Katayama, H. Kawakami, Y. Watanabe, H. Ishiyama, H. Miyatake, M. Sataka, S. Okayasu, H. Sugai, S. Ichikawa, K. Nishio, T. Nakanoya, N. Ishikawa, Y. Chimi, T. Hashimoto, M. Yahagi, K. Takada, B.C. Kim, M. Watanabe, A. Iwase, T. Hashimoto and T. Ishikawa 596

New developments in instrumentation and techniques

Detection of acoustic signals induced by heavy-ion impact: ion-beam seismology
T. Kambara 601
The use of MIM tunnel junctions to investigate kinetic electron excitation in atomic collision cascades
S. Meyer, D. Diesing and A. Wucher 608
Investigation of heavily damaged ion implanted Si by atomistic simulation of Rutherford backscattering channeling spectra
G. Lulli, E. Albertazzi, M. Bianconi, A. Satta, S. Balboni, L. Colombo and A. Uguzzoni 613
Studies of nanotube channeling for efficient beam scraping at accelerators
V.M. Biryukov and S. Bellucci 619

Author index 624